



Features

DMT10H015LPS

PowerDI5060-8

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | Ι _D T _C = +25°C |
|-------------------|------------------------------|--|
| 100\/ | 16mΩ @ V _{GS} = 10V | 44A |
| 100V | $18m\Omega @ V_{GS} = 6.0V$ | 41A |

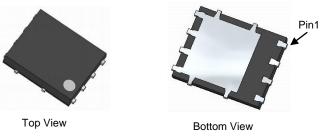
Description

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize $R_{DS(ON)}$, yet maintain superior switching performance. This device is ideal for use in notebook battery power management and loadswitch.

Applications

- Motor Control
- DC-DC Converters
- Power Management

PowerDI5060-8



Mechanical Data

High Conversion Efficiency

Low Input Capacitance Fast Switching Speed

Low R_{DS(ON)} – Minimizes On-State Losses

Lead-Free Finish; RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) Qualified to AEC-Q101 Standards for High Reliability

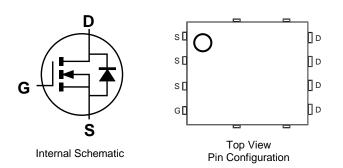
- Case: PowerDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0

100V N-CHANNEL ENHANCEMENT MODE MOSFET

<1.1mm Package Profile – Ideal for Thin Applications (PowerDI®)

Thermally Efficient Package - Cooler Running Applications

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

| Case | Packaging |
|---------------|-------------------|
| PowerDI5060-8 | 2,500/Tape & Reel |
| - | |

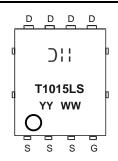
EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



)'' = Manufacturer's Marking
T1015LS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 17 = 2017)
WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|---|------------------|---|------------------|------------|----|
| Drain-Source Voltage | V _{DSS} | 100 | V | | |
| Gate-Source Voltage | | | V _{GSS} | ±20 | V |
| Continuous Drain Current (Noto 5) // 40// | Steady State | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | I _D | 7.3 5.8 | А |
| Continuous Drain Current (Note 5) $V_{GS} = 10V$ | Steady State | T _C = +25°C T _C = +100°C | ID | 44 28 | А |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | I _{DM} | 150 | A | | |
| Maximum Continuous Body Diode Forward Current (Note 5) | | | ls | 1.5 | A |
| Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%) | | | I _{SM} | 150 | А |
| Avalanche Current (Note 7) L = 3mH | | | I _{AS} | 7.5 | А |
| Avalanche Energy (Note 7) L = 3mH | | | E _{AS} | 85 | mJ |

Thermal Characteristics

| Characteristic | | Symbol | Value | Unit |
|--|----------------------------------|----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) | $T_A = +25^{\circ}C$ | PD | 1.3 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | | R _{0JA} | 98 | °C/W |
| Total Power Dissipation | $T_{\rm C} = +25^{\circ}{\rm C}$ | PD | 46 | W |
| Thermal Resistance, Junction to Case | | R _{θJC} | 2.7 | °C/W |
| Operating and Storage Temperature Range | | T _{J,} T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

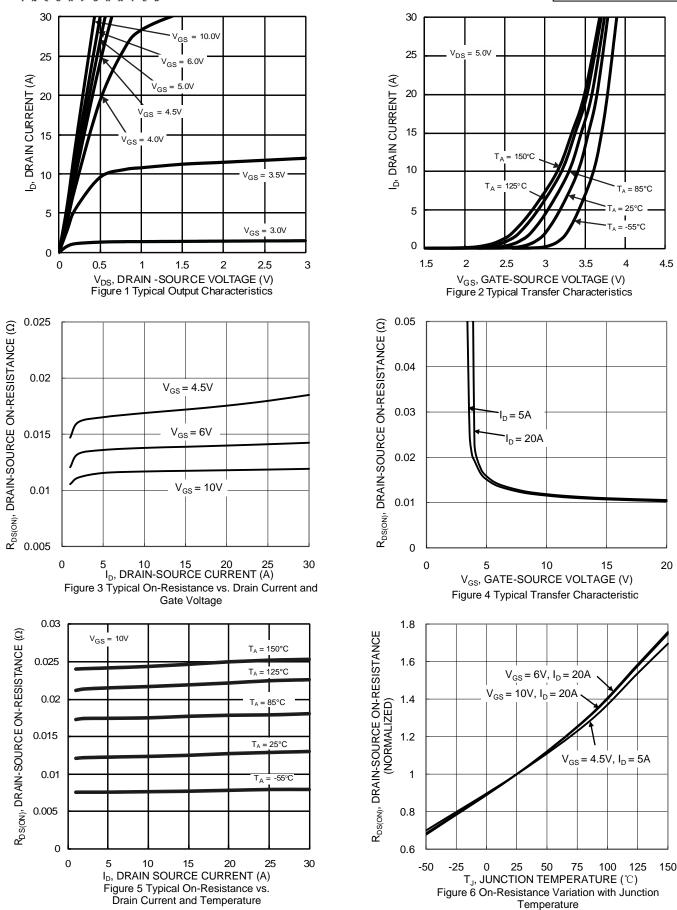
| | 1 | | I | I | I | |
|-----------------------------------|---------------------|-----|------|------|------|--|
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
| OFF CHARACTERISTICS (Note 6) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 100 | — | _ | V | $V_{GS} = 0V, I_D = 1mA$ |
| Zero Gate Voltage Drain Current | I _{DSS} | | — | 1 | μA | $V_{DS} = 80V, V_{GS} = 0V$ |
| Gate-Source Leakage | I _{GSS} | | — | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 6) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 1.4 | 2.3 | 3 | V | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ |
| | | _ | 11 | 16 | | $V_{GS} = 10V, I_D = 20A$ |
| Static Drain-Source On-Resistance | R _{DS(ON)} | _ | 13.5 | 18 | mΩ | $V_{GS} = 6V, I_D = 20A$ |
| | . , | _ | 18 | 25 | | $V_{GS} = 4.5V, I_D = 5A$ |
| Diode Forward Voltage | V _{SD} | _ | 0.9 | 1.3 | V | $V_{GS} = 0V, I_{S} = 20A$ |
| DYNAMIC CHARACTERISTICS (Note 7) | | | | | | |
| Input Capacitance | C _{iss} | _ | 1871 | — | pF | $V_{DS} = 50V, V_{GS} = 0V$ f = 1MHz |
| Output Capacitance | Coss | _ | 261 | _ | | |
| Reverse Transfer Capacitance | C _{rss} | _ | 6.9 | — | | |
| Gate Resistance | RG | _ | 0.75 | — | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ |
| Total Gate Charge | Q _G | _ | 33.3 | _ | | N/ 501/ 1 40A |
| Gate-Source Charge | Q _{GS} | _ | 6.9 | _ | nC | $V_{DD} = 50V, I_D = 10A,$ $V_{GS} = 10V$ |
| Gate-Drain Charge | Q _{GD} | _ | 5.1 | — | | |
| Turn-On Delay Time | t _{D(ON)} | | 6.5 | _ | | |
| Turn-On Rise Time | t _R | _ | 7.0 | _ | | $V_{DD} = 50V, V_{GS} = 10V,$ |
| Turn-Off Delay Time | t _{D(OFF)} | _ | 19.7 | — | ns | $I_D = 10A, R_G = 6\Omega$ |
| Turn-Off Fall Time | t _F | _ | 8.1 | — | 1 | |
| Reverse Recovery Time | t _{RR} | _ | 37.9 | _ | ns | |
| Reverse Recovery Charge | Q _{RR} | _ | 51.9 | _ | nC | I _F = 10A, di/dt = 100A/μs |

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Short duration pulse test used to minimize self-heating effect.
7. Guaranteed by design. Not subject to product testing.

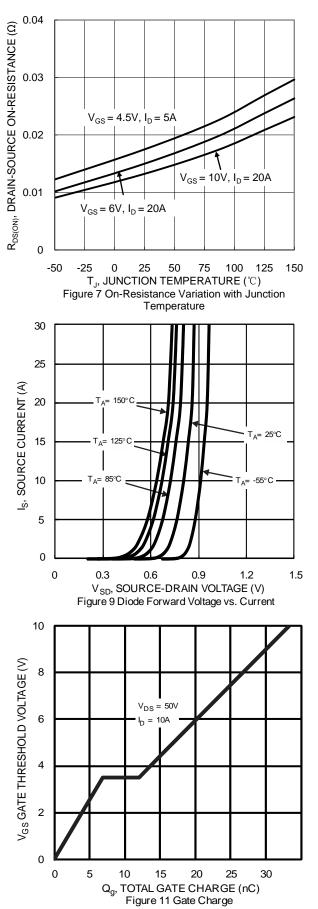


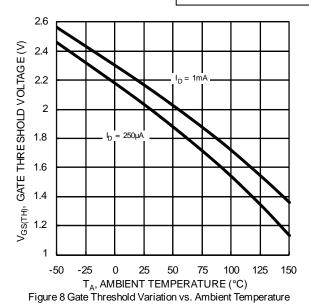


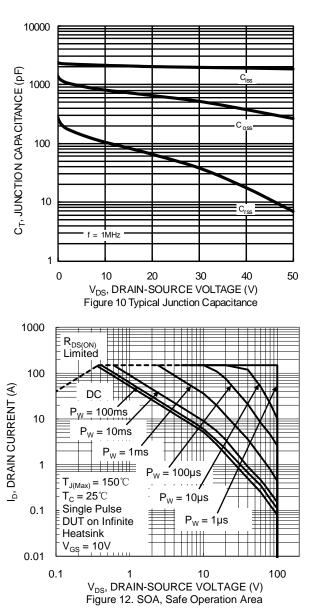




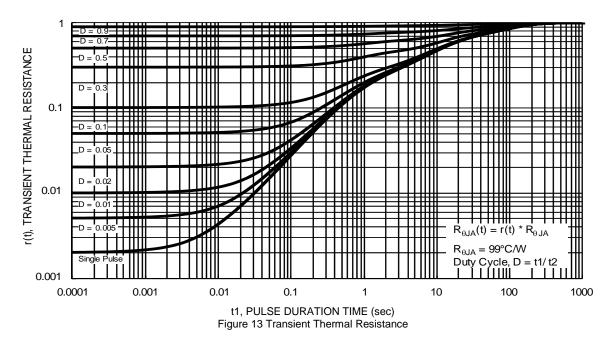
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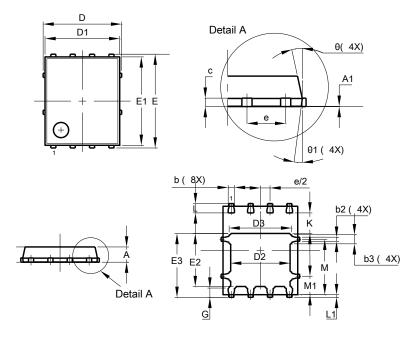




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

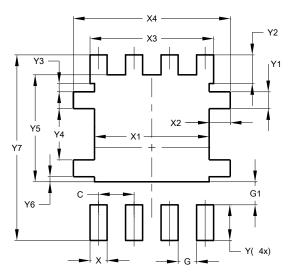


| | PowerDI5060-8 | | | | | |
|----------------------|---------------|----------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.90 | 1.10 | 1.00 | | | |
| A1 | 0.00 | 0.05 | _ | | | |
| b | 0.33 | 0.51 | 0.41 | | | |
| b2 | 0.200 | 0.350 | 0.273 | | | |
| b3 | 0.40 | 0.80 | 0.60 | | | |
| С | 0.230 | 0.330 | 0.277 | | | |
| D | | 5.15 BSC | | | | |
| D1 | 4.70 | 5.10 | 4.90 | | | |
| D2 | 3.70 | 4.10 | 3.90 | | | |
| D3 | 3.90 | 4.30 | 4.10 | | | |
| E | | 6.15 BSC | ; | | | |
| E1 | 5.60 | 6.00 | 5.80 | | | |
| E2 | 3.28 | 3.68 | 3.48 | | | |
| E3 | 3.99 | 4.39 | 4.19 | | | |
| е | 1.27 BSC | | | | | |
| G | 0.51 | 0.71 | 0.61 | | | |
| K | 0.51 | - | - | | | |
| L | 0.51 | 0.71 | 0.61 | | | |
| L1 | 0.100 | 0.200 | 0.175 | | | |
| Μ | 3.235 | 4.035 | 3.635 | | | |
| M1 | 1.00 | 1.40 | 1.21 | | | |
| Θ | 10° | 12° | 11° | | | |
| Θ1 | 6° | 8° | 7° | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



| Dimensions | Value (in mm) | | |
|------------|---------------|--|--|
| С | 1.270 | | |
| G | 0.660 | | |
| G1 | 0.820 | | |
| Х | 0.610 | | |
| X1 | 4.100 | | |
| X2 | 0.755 | | |
| X3 | 4.420 | | |
| X4 | 5.610 | | |
| Y | 1.270 | | |
| Y1 | 0.600 | | |
| Y2 | 1.020 | | |
| Y3 | 0.295 | | |
| Y4 | 1.825 | | |
| Y5 | 3.810 | | |
| Y6 | 0.180 | | |
| Y7 | 6.610 | | |



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